

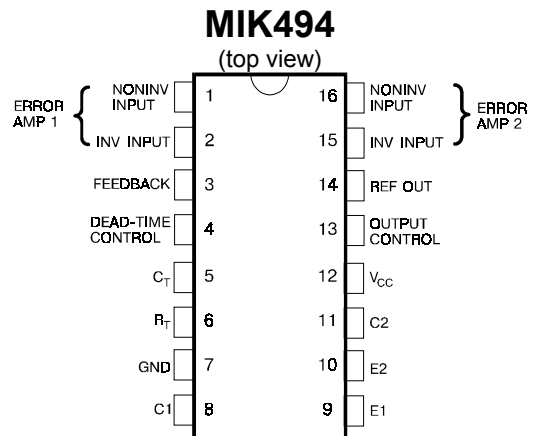
Description

The MIK494 incorporate on a single monolithic chip all the functions required in the construction of a pulse-width-modulation control circuit. Designed primarily for power supply control, these devices offer the systems engineer the flexibility to tailor the power supply control circuitry to his application.

The MIK494 contains an error amplifier, an on-chip adjustable oscillator, a dead-time control comparator, pulse-steering control flip-flop, a 5-volt, 5% precision regulator, and output-control circuits. The error amplifier exhibits a common-mode voltage range from -0.3 volts to $V_{CC} - 2$ volts. The dead-time control comparator has a fixed offset that provides approximately 5% dead time when externally altered. The on-chip oscillator may be bypassed by terminating R_T (pin 6) to the reference output and providing a sawtooth input to C_T (pin 5), or it may be used to drive the common circuits in synchronous multiple-rail power supplies. The uncommitted output transistors provide either common-emitter or emitter-follower output capability. Each device provides for push-pull or single-ended output operation, which may be selected through the output-control function. The architecture of these devices prohibits the possibility of either output being pulsed twice during push-pull operation.

Features

- Complete PWM Power Control Circuitry
- Uncommitted Outputs for 200 mA Sink or Source Current
- Output Control Selects Single-Ended or Push-Pull Operation
- Internal Circuitry Prohibits Double Pulse at Either Output
- Variable Dead-Time Provides Control over Total Range
- Internal Regulator Provides a Stable 5-V Reference Supply, 5%
- Circuit Architecture Allows Easy Synchronization



Absolute Maximum Ratings

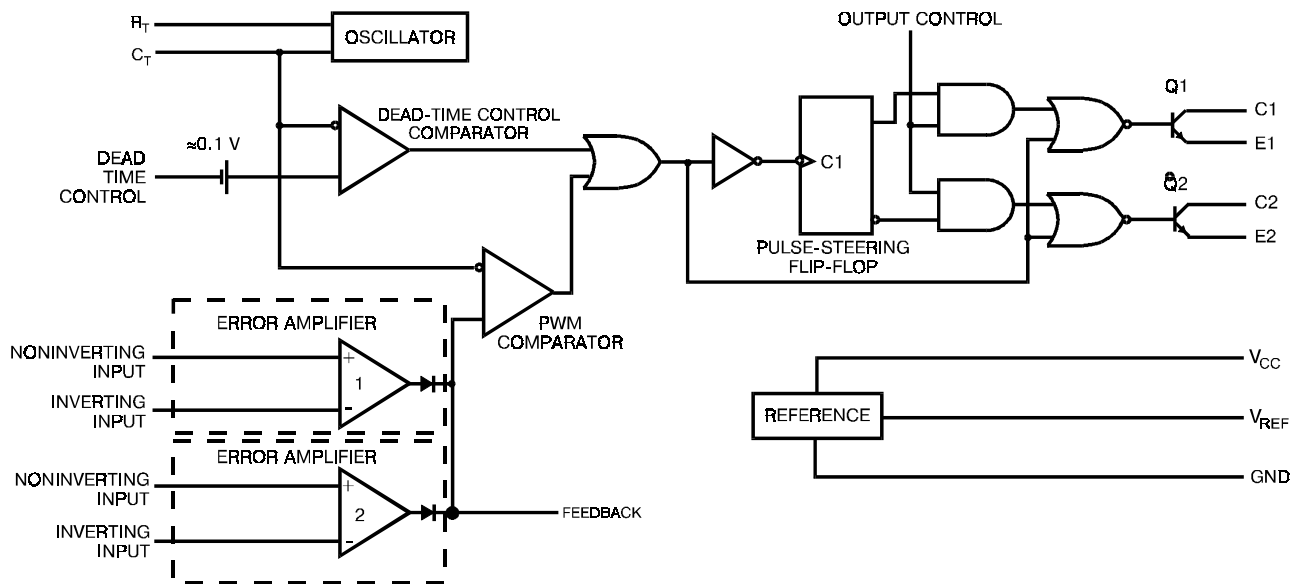
over operating free-air temperature range (unless otherwise noted)

Parameter	Maximum	Units
Supply voltage, V_{CC}	41	V
Amplifier input voltage	$V_{CC} + 0.3$	
Collector output voltage	41	
Collector output current	250	mA
Operating free-air temperature range	0 to 70	°C
Storage temperature range	-65 to 150	
Lead temperature 1.6 mm from case for 10 seconds	260	

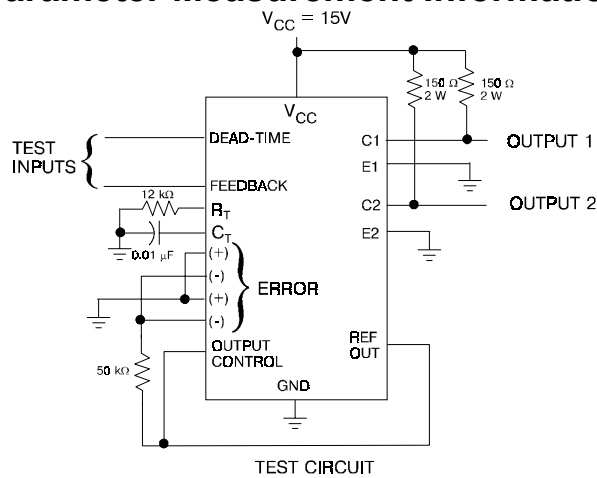
Recommended Operating Conditions

Parameter	MIK494		Units
	Min	Max	
Supply voltage, V_{CC}	7	40	V
Amplifier input voltage, V_i	-0.3	$V_{CC} - 2$	
Collector output voltage, V_o		40	
Collector output current (each transistor)		200	mA
Current into feedback terminal		0.3	
Timing capacitor, C_T	0.47	10000	nF
Timing resistor, R_T	1.8	500	k Ω
Oscillator frequency	1	300	kHz
Operating free-air temperature, T_A	0	70	°C

Functional Block Diagram



Parameter Measurement Information



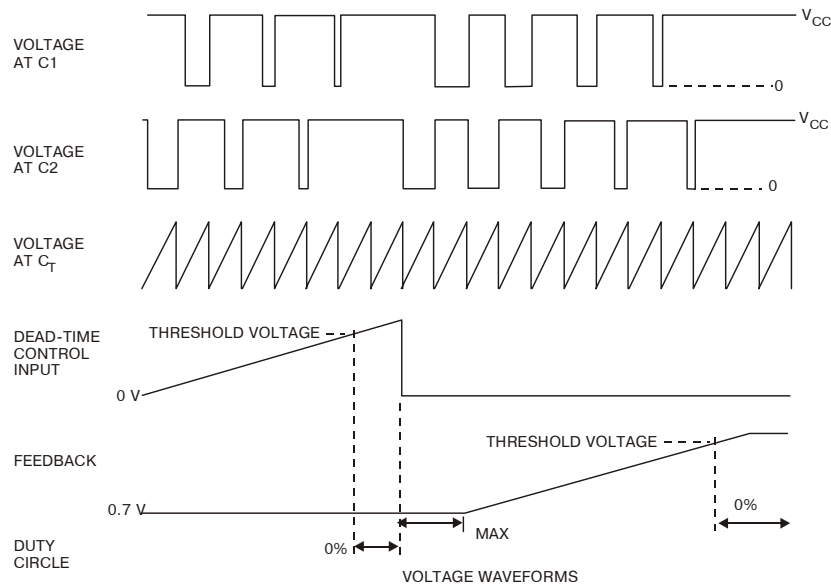


Figure 1. Operational test circuit and waveforms

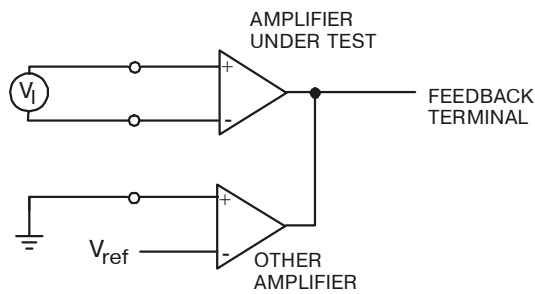


Figure 2. Amplifier characteristics

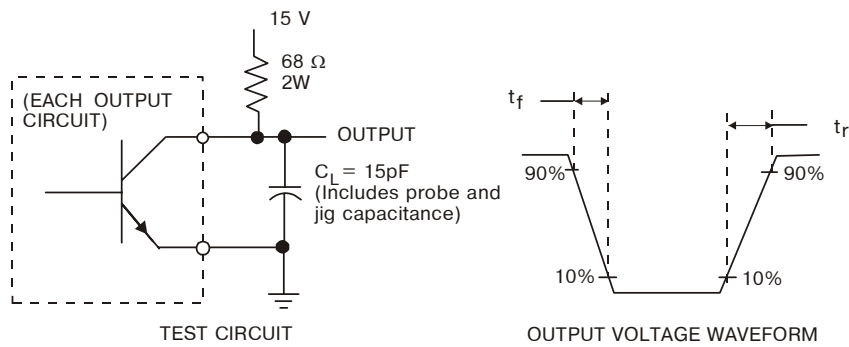


Figure 3. Common-emitter configuration

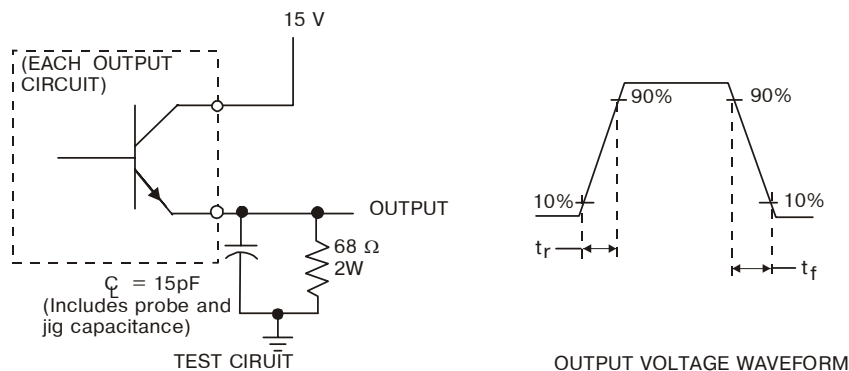


Figure 4. Emitter-follower configuration

Electrical Characteristics

over recommended operating free-air temperature range, $V_{CC}=15V$, $f=10kHz$ (unless otherwise noted)

Reference Section

Parameter	Test conditions*	Value			Units
		Min	Typ**	Max	
Output voltage (V_{ref})	$I_O = 1mA$	4.75	5	5.25	V
Input regulation	$V_{CC} = 7V$ to $40V$		2	25	mV
Output regulation	$I_O = 1mA$ to $10mA$		1	15	
Output voltage change with temperature	$\Delta T_A = MIN$ to MAX		0.2	1	%
Short-circuit output current***	$V_{ref} = 0$		35		mA

Oscillator Section (see Figure 1)

Parameter	Test conditions*	Value			Units
		Min	Typ**	Max	
Frequency	$C_T = 0.01 \mu F$, $R_T = 12k\Omega$		10		kHz
Standard deviation of frequency ****	All values of V_{CC} , C_T , R_T , and T_A constant		10		%
Frequency change with voltage	$V_{CC} = 7V$ to $40V$, $T_A = 25^\circ C$		0.1		
Frequency change with temperature *****	$C_T = 0.01 \mu F$, $R_T = 12k\Omega$, $\Delta T_A = MIN$ to MAX			1	

Amplifier Section (see Figure 2)

Parameter	Test conditions*	Value			Units
		Min	Typ**	Max	
Input offset voltage	V_O (pin 3) = $2.5V$		2	10	mV
Input offset current	V_O (pin 3) = $2.5V$		25	250	nA
Input bias current	V_O (pin 3) = $2.5V$		0.2	1	μA
Common-mode input voltage range	$V_{CC} = 7V$ to $40V$	-0.3 to $V_{CC}-2$			V
Open-loop voltage amplification	$\Delta V_O = 3V$, $R_L = 2k\Omega$, $V_O = 0.5$ to $3.5V$	70	95		dB
Unity-gain bandwidth	$V_O = 0.5$ to $3.5V$, $R_L = 2k\Omega$		800		kHz
Common-mode rejection ratio	$\Delta V_O = 40V$, $T_A = 25^\circ C$	65	80		dB
Output sink current (pin 3)	$V_{ID} = -15mV$ to $-5V$, $V_{(pin3)} = 0.7V$	0.3	0.7		mA
Output source current (pin 3)	$V_{ID} = 15mV$ to $5V$, $V_{(pin3)} = 3.5V$	-2			mA

* For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

** All typical values except for parameter changes with temperature are at $T_A = 25^\circ C$

*** Duration of the short-circuit should not exceed one second.

**** Standard deviation is a measure of the statistical distribution about the mean as derived from the formula

$$\sigma = \left[\frac{\sum_{n=1}^N (x_n - \bar{x})^2}{N-1} \right]^{1/2}$$

***** Temperature coefficient of timing capacitor and timing resistor not taken into account

Output section

Parameter	Test conditions	Value			Units
		Min	Typ*	Max	
Collector off-state current	$V_{CE}=40V$, $V_{CC}=40V$		2	100	μA
Emitter off-state current	$V_{CC}=V_C=40V$, $V_E=0$			-100	
Collector-emitter saturation voltage	Common-emitter		1.1	1.3	V
	Emitter-follower		1.5	2.5	
Output control input current	$V_I=V_{ref}$			3.5	mA

Dead-time control-section (see Figure 1)

Parameter	Test conditions	Value			Units
		Min	Typ*	Max	
Input bias current (pin 4)	$V_I=0$ to $5.25V$		-2	-10	μA
Maximum duty cycle, each output	$V_{I(p4)}=0$, $C_T=0.1\mu F$, $R_T=12k\Omega$		45		%
Input threshold voltage (pin 4)	Zero duty cycle		3	3.3	V
	Maximum duty cycle	0			

PWM Comparator Section (see Figure 1)

Parameter	Test conditions	Value			Units
		Min	Typ*	Max	
Input threshold voltage (pin 3)	Zero duty cycle		4	4.5	V
Input sink current (pin 3)	$V_{(pin\ 3)} = 0.7V$	0.3	0.7		mA

Total Device

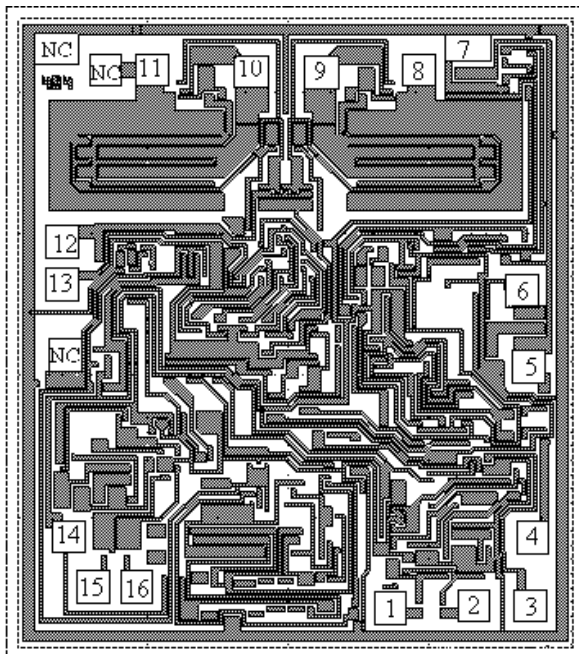
Parameter	Test conditions	Value			Units
		Min	Typ*	Max	
Standby supply current	Pin 6 at V_{ref} , all other inputs and outputs open	$V_{CC}=15V$	6	10	mA
		$V_{CC}=40V$	9	15	
Average supply current	$V_{I(p\in 4)}=2V$, See Figure 1		7.5		

Switching Characteristics, $T_A = 25^\circ C$

Parameter	Test conditions	Value			Units
		Min	Typ*	Max	
Output voltage rise time	Common-emitter configuration,		100	200	ns
Output voltage fall time	See figure 3		25	100	
Output voltage rise time	Emitter-follower configuration.		100	200	
Output voltage fall time	See Figure 4		40	100	

*All typical values except for temperature coefficient are at $T_A=25^\circ C$

Pad Location MIK494



Chip size 2.05x2.3 mm

Pad location coordinates

Pad N	Pad Name	Coordinates (μm)	
		X	Y
1	NONINV INPUT	1305	120
2	INV INPUT	1600	130
3	FEEDBACK	1800	130
4	DEAD-TIME CONTROL	1810	370
5	C_T	1795	975
6	R_T	1770	1240
7	GND	1520	2135
8	C1	1405	2020
9	E1	1055	2015
10	E2	805	2015
11	C2	460	2020
12	V_{CC}	140	1410
13	OUTPUT CONTROL	140	1260
14	REF OUT	160	375
15	INV INPUT	250	195
16	NONINV INPUT	405	195